

General Description

The MY30N02D uses advanced trench technology to provide excellent $R_{DS(ON)}$, low gate charge and operation with gate voltages as low as 4.5V. This device is suitable for use as a Battery protection or in other Switching application.

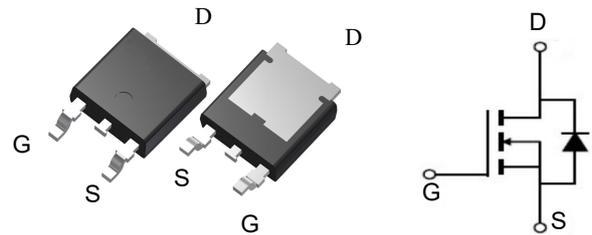


Features

| | | |
|----------------------------------|-----|------------|
| V_{DSS} | 20 | V |
| I_D | 30 | A |
| $R_{DS(ON)}$ (at $V_{GS}=10V$) | <15 | m Ω |
| $R_{DS(ON)}$ (at $V_{GS}=4.5V$) | <18 | m Ω |

Application

- Battery protection
- Load switch
- Uninterruptible power supply



Package Marking and Ordering Information

| Product ID | Pack | Marking | Qty(PCS) |
|------------|-----------|----------|----------|
| MY30N02D | TO-252-2L | MY30N02D | 2500 |

Absolute Maximum Ratings ($T_c=25^\circ\text{C}$ unless otherwise noted)

| Symbol | Parameter | Rating | Units |
|-------------------------------|--|------------|---------------------------|
| V_{DS} | Drain-Source Voltage | 20 | V |
| V_{GS} | Gate- Source Voltage | ± 12 | V |
| $I_D @ T_c=25^\circ\text{C}$ | Continuous Drain Current, $V_{GS} @ 10V^1$ | 30 | A |
| $I_D @ T_c=100^\circ\text{C}$ | Continuous Drain Current, $V_{GS} @ 10V^1$ | 15 | A |
| $I_D @ T_A=25^\circ\text{C}$ | Continuous Drain Current, $V_{GS} @ 10V^1$ | 7.3 | A |
| $I_D @ T_A=70^\circ\text{C}$ | Continuous Drain Current, $V_{GS} @ 10V^1$ | 5.8 | A |
| I_{DM} | Pulsed Drain Current ² | 50 | A |
| EAS | Single Pulse Avalanche Energy ³ | 8.1 | mJ |
| I_{AS} | Avalanche Current | 12.7 | A |
| $P_D @ T_c=25^\circ\text{C}$ | Total Power Dissipation ⁴ | 20.8 | W |
| $P_D @ T_A=25^\circ\text{C}$ | Total Power Dissipation ⁴ | 2 | W |
| T_{STG} | Storage Temperature Range | -55 to 150 | $^\circ\text{C}$ |
| T_J | Operating Junction Temperature Range | -55 to 150 | $^\circ\text{C}$ |
| $R_{\theta JA}$ | Thermal Resistance Junction-ambient ¹ | 62 | $^\circ\text{C}/\text{W}$ |
| $R_{\theta JC}$ | Thermal Resistance Junction-Case ¹ | 6 | $^\circ\text{C}/\text{W}$ |

Electrical Characteristics (T_J=25 °C, unless otherwise noted)

| Symbol | Parameter | Conditions | Min. | Typ. | Max. | Unit |
|-------------------------------------|--|--|------|-------|------|--------|
| BV _{DSS} | Drain-Source Breakdown Voltage | V _{GS} =0V, I _D =250uA | 20 | --- | --- | V |
| ΔBV _{DSS} /ΔT _J | BVDSS Temperature Coefficient | Reference to 25C, I _D =1mA | --- | 0.023 | --- | V/ °C |
| R _{DS(ON)} | Static Drain-Source On-Resistance ² | V _{GS} =4.5V, I _D =10A | --- | 10 | 15 | mΩ |
| | | V _{GS} =2.5V, I _D =8A | | 13 | 18 | |
| V _{GS(th)} | Gate Threshold Voltage | V _{GS} =V _{DS} , I _D =250uA | 0.5 | | 1.2 | V |
| ΔV _{GS(th)} | V _{GS(th)} Temperature Coefficient | | --- | -4.2 | --- | mV/ °C |
| I _{DSS} | Drain-Source Leakage Current | V _{DS} =24V, V _{GS} =0V, T _J =25C | --- | --- | 1 | uA |
| | | V _{DS} =24V, V _{GS} =0V, T _J =55C | --- | --- | 5 | |
| I _{GSS} | Gate-Source Leakage Current | V _{GS} = ±20V, V _{DS} =0V | --- | --- | ±100 | nA |
| g _{fs} | Forward Transconductance | V _{DS} =5V, I _D =10A | --- | 5.5 | --- | S |
| R _g | Gate Resistance | V _{DS} =0V, V _{GS} =0V, f=1MHz | --- | 2.3 | --- | Ω |
| Q _g | Total Gate Charge (4.5V) | V _{DS} =15V, V _{GS} =4.5V, I _D =10A | --- | 4.9 | --- | nC |
| Q _{gs} | Gate-Source Charge | | --- | 1.66 | --- | |
| Q _{gd} | Gate-Drain Charge | | --- | 1.85 | --- | |
| T _{d(on)} | Turn-On Delay Time | V _{DD} =15V, V _{GS} =10V, R _G =3.3, I _D =10A | --- | 1.6 | --- | ns |
| T _r | Rise Time | | --- | 15.8 | --- | |
| T _{d(off)} | Turn-Off Delay Time | | --- | 13 | --- | |
| T _f | Fall Time | | --- | 4.8 | --- | |
| C _{iss} | Input Capacitance | V _{DS} =15V, V _{GS} =0V, f=1MHz | --- | 416 | --- | pF |
| C _{oss} | Output Capacitance | | --- | 62 | --- | |
| C _{rss} | Reverse Transfer Capacitance | | --- | 51 | --- | |
| I _S | Continuous Source Current ^{1,5} | V _G =V _D =0V, Force Current | --- | --- | 24 | A |
| I _{SM} | Pulsed Source Current ^{2,5} | | --- | --- | 50 | A |
| V _{SD} | Diode Forward Voltage ² | V _{GS} =0V, I _S =1A, T _J =25C | --- | --- | 1.2 | V |
| t _{rr} | Reverse Recovery Time | I _F =10A, di/dt=100A/μs, T _J =25 °C | --- | 8.7 | --- | nS |
| Q _{rr} | Reverse Recovery Charge | | --- | 1.95 | --- | nC |

Note :

- 1.The data tested by surface mounted on a 1 inch² FR-4 board with 2OZ copper.
- 2The data tested by pulsed , pulse width .The EAS data shows Max. rating .
- 3he test condition is V_{GS} ≤ 300us , duty cycle $\frac{t_{ON}}{T} \leq 25\%$, V_{GS} =10V, L=0.1mH, I_{AS}=12.7A
- 4.The power dissipation is limited by 150C junction temperature
- 5.The data is theoretically the same as I_D and I_{DM}, in real applications , should be limited by total power dissipation.

Typical Characteristics

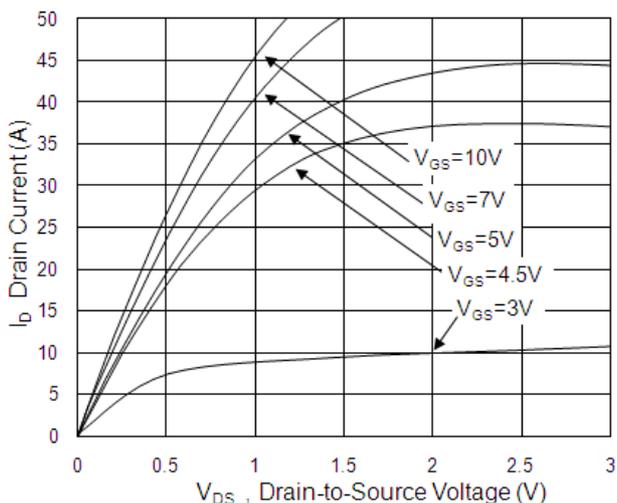


Fig.1 Typical Output Characteristics

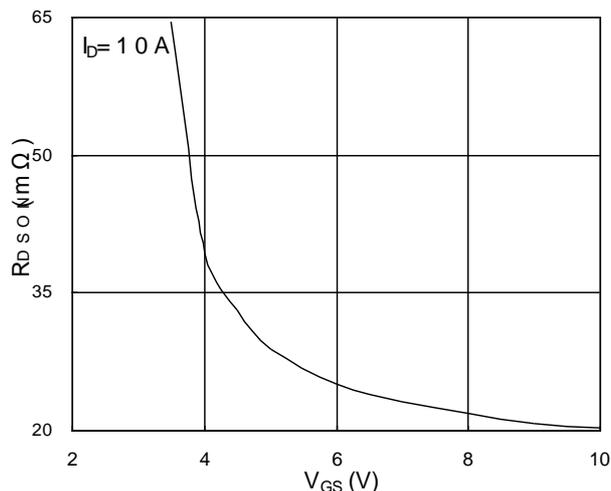


Fig.2 On-Resistance vs. Gate-Source

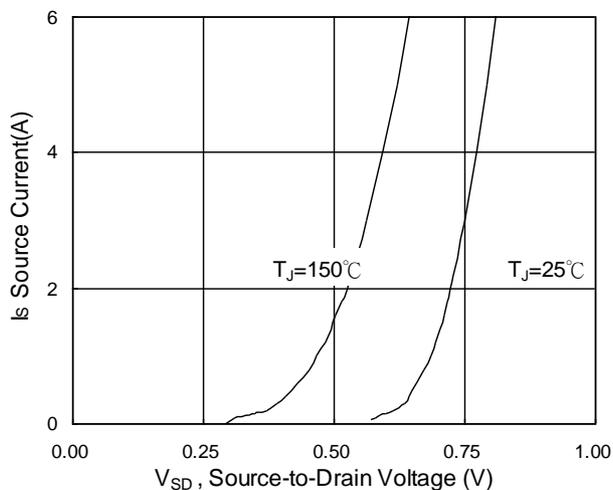


Fig.3 Forward Characteristics Of Reverse

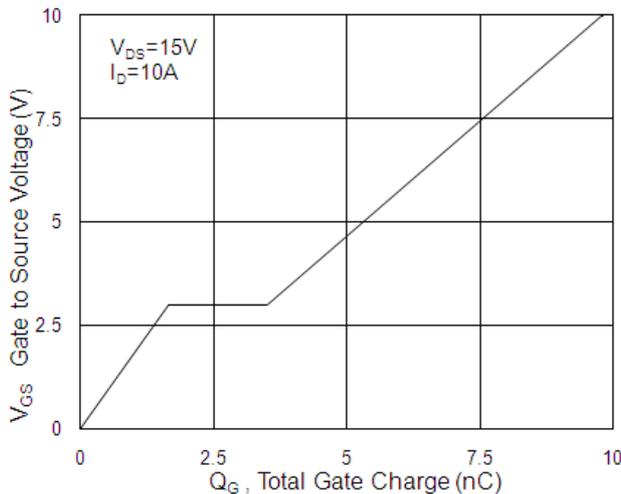


Fig.4 Gate-Charge Characteristics

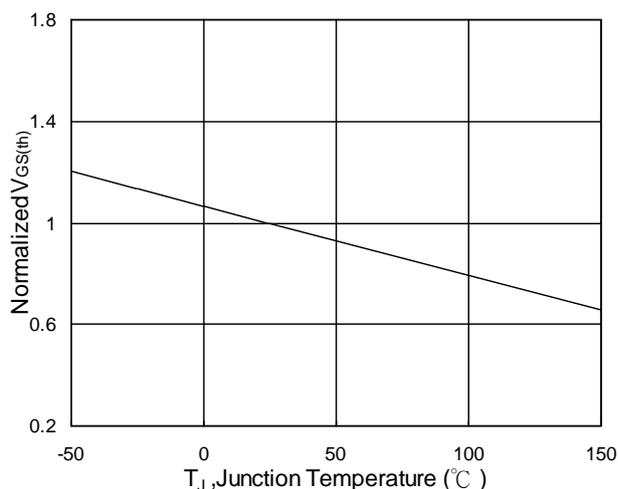


Fig.5 Normalized $V_{GS(th)}$ vs. T_J

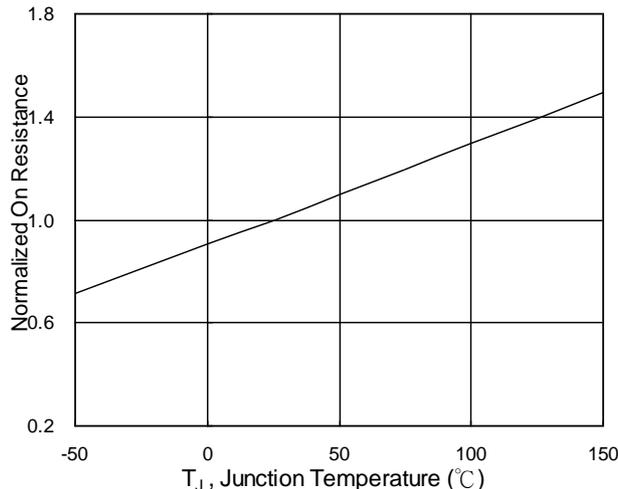


Fig.6 Normalized $R_{DS(on)}$ vs. T_J

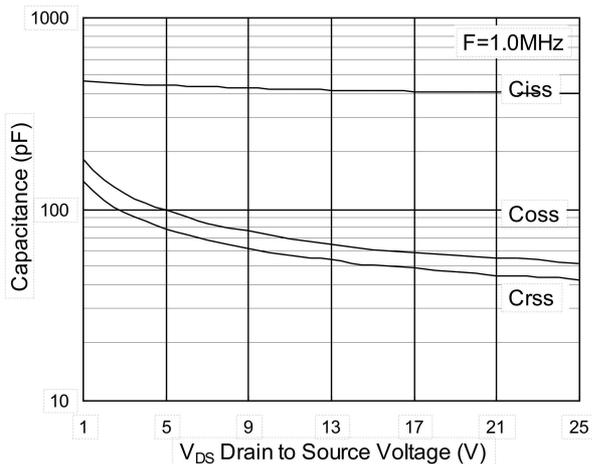


Fig.7 Capacitance

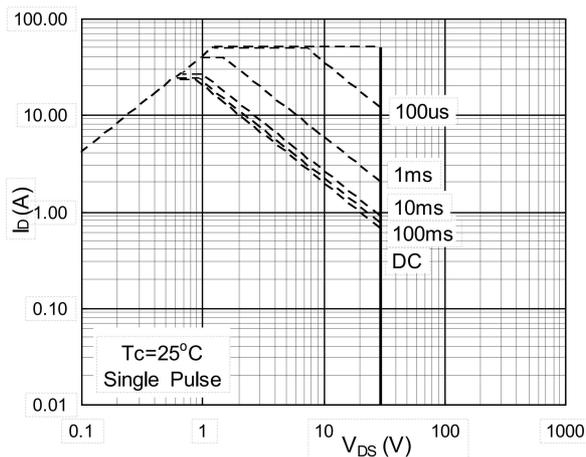


Fig.8 Safe Operating Area

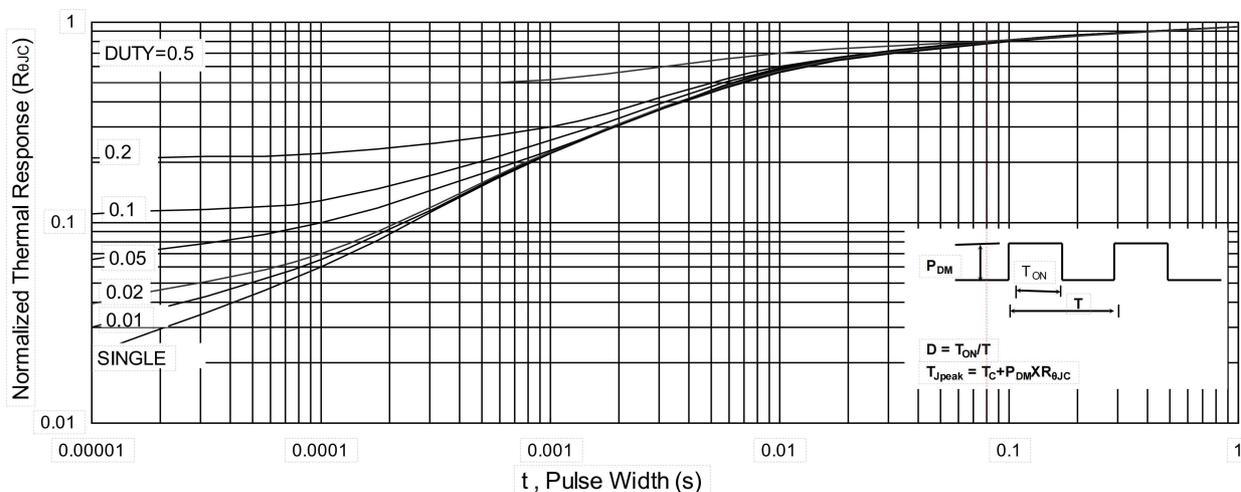


Fig.9 Normalized Maximum Transient Thermal Impedance

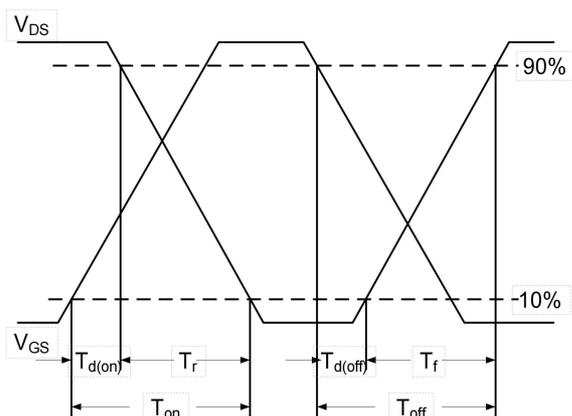


Fig.10 Switching Time Waveform

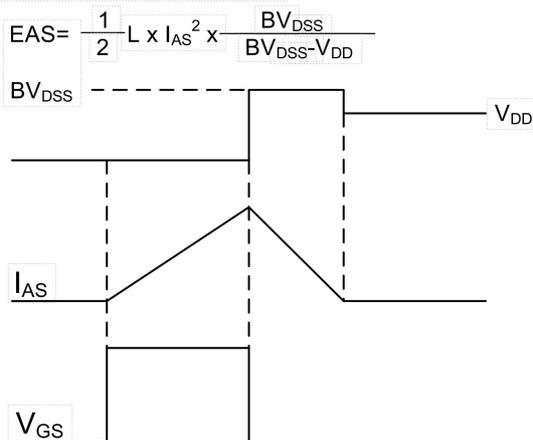
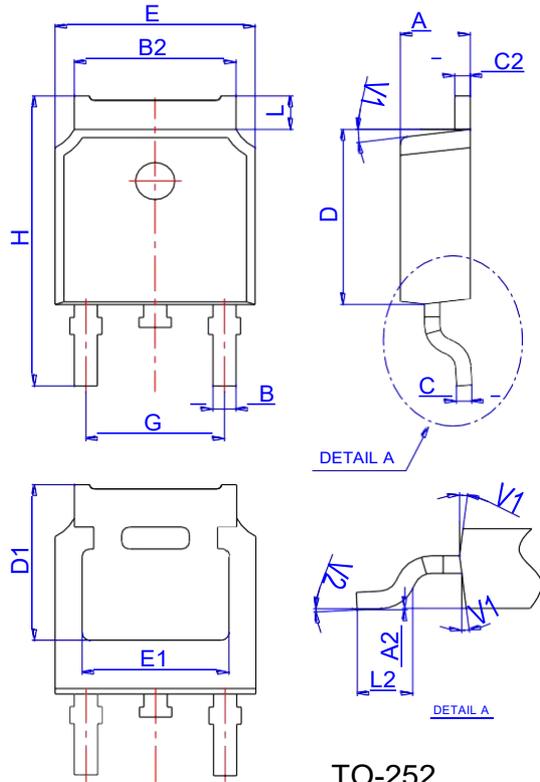


Fig.11 Unclamped Inductive Switching Waveform

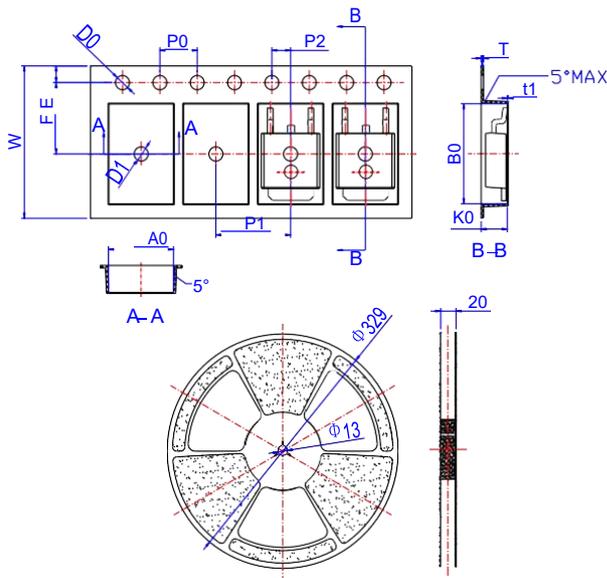
Package Mechanical Data



TO-252

| Ref. | Dimensions | | | | | |
|------|-------------|------|-------|----------|------|-------|
| | Millimeters | | | Inches | | |
| | Min. | Typ. | Max. | Min. | Typ. | Max. |
| A | 2.10 | | 2.50 | 0.083 | | 0.098 |
| A2 | 0 | | 0.10 | 0 | | 0.004 |
| B | 0.66 | | 0.86 | 0.026 | | 0.034 |
| B2 | 5.18 | | 5.48 | 0.202 | | 0.216 |
| C | 0.40 | | 0.60 | 0.016 | | 0.024 |
| C2 | 0.44 | | 0.58 | 0.017 | | 0.023 |
| D | 5.90 | | 6.30 | 0.232 | | 0.248 |
| D1 | 5.30REF | | | 0.209REF | | |
| E | 6.40 | | 6.80 | 0.252 | | 0.268 |
| E1 | 4.63 | | | 0.182 | | |
| G | 4.47 | | 4.67 | 0.176 | | 0.184 |
| H | 9.50 | | 10.70 | 0.374 | | 0.421 |
| L | 1.09 | | 1.21 | 0.043 | | 0.048 |
| L2 | 1.35 | | 1.65 | 0.053 | | 0.065 |
| V1 | | 7° | | | 7° | |
| V2 | 0° | | 6° | 0° | | 6° |

Reel Specification-TO-252



| Ref. | Dimensions | | | | | |
|------|-------------|-------|-------|--------|-------|-------|
| | Millimeters | | | Inches | | |
| | Min. | Typ. | Max. | Min. | Typ. | Max. |
| W | 15.90 | 16.00 | 16.10 | 0.626 | 0.630 | 0.634 |
| E | 1.65 | 1.75 | 1.85 | 0.065 | 0.069 | 0.073 |
| F | 7.40 | 7.50 | 7.60 | 0.291 | 0.295 | 0.299 |
| D0 | 1.40 | 1.50 | 1.60 | 0.055 | 0.059 | 0.063 |
| D1 | 1.40 | 1.50 | 1.60 | 0.055 | 0.059 | 0.063 |
| P0 | 3.90 | 4.00 | 4.10 | 0.154 | 0.157 | 0.161 |
| P1 | 7.90 | 8.00 | 8.10 | 0.311 | 0.315 | 0.319 |
| P2 | 1.90 | 2.00 | 2.10 | 0.075 | 0.079 | 0.083 |
| A0 | 6.85 | 6.90 | 7.00 | 0.270 | 0.271 | 0.276 |
| B0 | 10.45 | 10.50 | 10.60 | 0.411 | 0.413 | 0.417 |
| K0 | 2.68 | 2.78 | 2.88 | 0.105 | 0.109 | 0.113 |
| T | 0.24 | | 0.27 | 0.009 | | 0.011 |
| t1 | 0.10 | | | 0.004 | | |
| 10P0 | 39.80 | 40.00 | 40.20 | 1.567 | 1.575 | 1.583 |